# **General Purpose Silicon Rectifiers**



A1N4007G-G

# Voltage: 1000 V

Current: 1.0 A

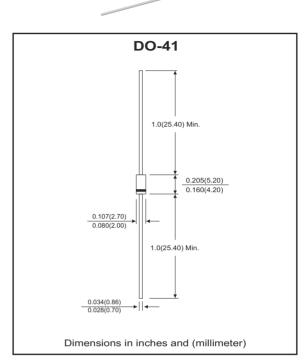
**RoHS Device** 

#### Features

- Low drop down voltage
- High current capability
- Low reverse leakage.
- High forward surge current capability.
- Glass passivated chip junction.
- Comply with AEC-Q101

#### **Mechanical data**

- Case: JEDEC DO-41 molded plastic
- Epoxy: UL 94V-0 rate flame retardant
- Terminals: Solderable per MIL-STD-750 method 2026.
- Polarity: Color band denotes cathode end
- Mounting position: Any
- Weight: 0.34 grams(approx.)



#### **Circuit diagram**

### Maximum Ratings and Electrical Characteristics (at Ta=25°C unless otherwise noted)

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load derate current by 20%.

Parameter	Conditions	Symbol	Value	Unit
Maximum recurrent peak reverse voltage		Vrrm	1000	V
Maximum RMS voltage		Vrms	700	V
Maximum DC blocking voltage		VDC	1000	V
Maximum average forward rectified current	see figure 1	I(AV)	1	А
Peak forward surge current	8.3mS single half sine-wave superimposed on rated load (JEDEC Method) TL=110°C	Ігѕм	30	А
Maximum instantaneous forward voltage	@IF = 1A	VF	1.1	V
Maximum DC reverse current	T <sub>A</sub> = 25°C	lr,	5	μΑ
at rated DC blocking voltage	T <sub>A</sub> = 125°C		50	
Typical junction Capacitance	V <sub>R</sub> = 4V, f = 1MHz	CJ	10	pF
Typical thermal resistance	Junction to ambient	Roja	45	°C/W
Operating junction temperature range		TJ	-55 ~ +125	°C
Storage temperature range		Tstg	-55 ~ +150	°C

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#### Rating and Characteristic Curves (A1N4007G-G)

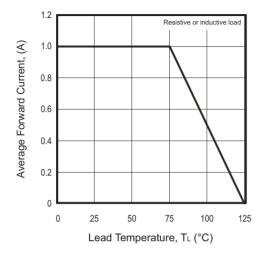


Fig.1 - Forward Current Derating Curve



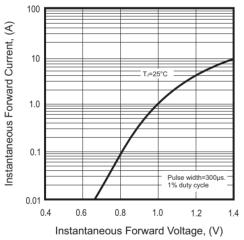
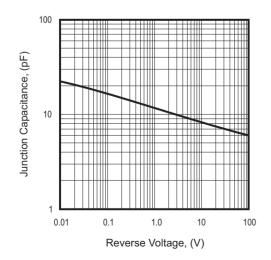


Fig.5 - Typical Junction Capacitance



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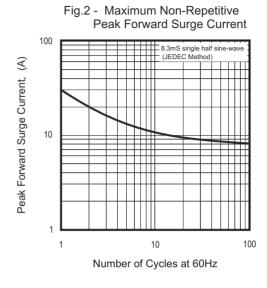
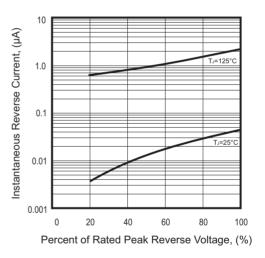
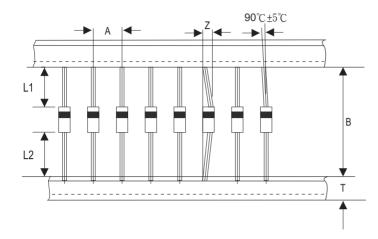


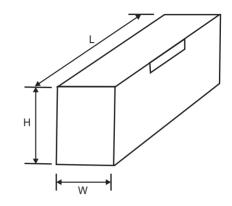
Fig.4 - Typical Reverse Characteristics





### **Taping Specification For Axial Lead Diodes**





	SYMBOL	Α	В	Z	Т	L1	L2
DO-41	(mm)	$\textbf{5.00} \pm \textbf{0.50}$	52.00 ± 0.50	1.20 (max)	6.00 ± 0.40	1.00 (max)	1.00 (max)
	(inch)	0.197 ± 0.020	$\textbf{2.047} \pm \textbf{0.020}$	0.047 (max)	$0.236 \pm 0.016$	0.039 (max)	0.039 (max)
	SYMBOL	L	W	Н			
DO-41	SYMBOL (mm)	L 260.00 ± 10.00	W 75.00 ± 10.00	H 140.00 ± 10.00			

1N4007G

## **Marking Code**

Part Number	Marking Code
A1N4007G-G	1N4007G



## **Standard Packaging**

	AMMO PACK		
Case Type	BOX ( pcs )	CARTON ( pcs )	
DO-41	5,000	50,000	

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